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TRANSMITTA	Application Number		10/714,307			
OIA FORM	Filing Date N		November 14, 2003			
(to be used for all correspondence after to	(to be used for all correspondence after initial filing)			Xeuping Xu		
FEB 2 4 2004	:	Group Art Unit		TBA		
		Examiner Name		ТВА		
Total Number of Pages in This Sub	mission	Attorney Docket Nun	nber	ATMI-687		
	ENCLOSURES	(check all that apply	y)			
Fee Transmittal Form	Assignr	nent Papers Application)	TC	After Allowance Communication to Group		
Fee Attached	Drawing	g(s)		Appeal Communication to Board of Appeals and Interferences		
Amendment / Reply	Licensin	ng-related Papers	lated Papers Appeal Communicatio (Appeal Notice, Brief, Rep			
After Final	Petition			Proprietary Information		
Affidavits/declaration(s)		to Convert to a nal Application		Status Letter		
Extension of Time Request	Power of Attorney, Revocation Change of Correspondence Address			Other Enclosure(s) (please identify below):		
Express Abandonment Request		al Disclaimer	Cor	pies of 7 References		
Information Disclosure Statement	Information Disclosure Statement Reques					
Certified Copy of Priority Document(s)	CD, Nu	mber of CD(s)				
Response to Missing Parts/ Incomplete Application Response to Missing Parts under 37 CFR 1.52 or 1.53	Incomplete Application Response to Missing Parts					
SIGNAT	URE OF APPLIC	CANT, ATTORNEY, C	RAG	ENT		
Firm William F. Ryann, F Individual name	Reg. No. 44,313					
Signature Signature						
Date February 19, 2004	Date February 19, 2004					
CERTIFICATE OF MAILING						
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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Xeuping Xu, et al.

Group Art Unit: TBA

U.S. Application No.: 10/714,307

Examiner: TBA

Filed: November 14, 2003

Title: VICINAL GALLIUM NITRIDE SUBSTRATE FOR HIGH QUALITY HOMOEPITAXY

CERTIFICATE OF MAILING

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on the date indicated below and is addressed to the Commissioner of Patents, P.O. Box 1450, Alexandria, VA

Lee Ann DiLello February 19, 2004

Date

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Pursuant to 37 C.F.R. §1.56, the attention of the Patent and Trademark Office is hereby directed to the reference(s) listed on the attached PTO-1449. It is respectfully requested that the information be expressly considered during the prosecution of this application, and that the reference(s) be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

■ 1. This Information Disclosure Statement is being filed within three months of the U.S. filing date OR before the mailing date of a first Office Action on the merits. No certification or fee is required in accordance with 37 CFR § 1.56 and § 1.97(b).

2.	U.S. fi	nformation Disclosure Statement is being filed more than three months after the ling date AND after the mailing date of the first Office Action on the merits, but the mailing date of a Final Rejection or Notice of Allowance.			
	□ a.	I hereby certify that each item of information contained in this Information Disclosure Statement was the first citation of such item by a foreign patent office in a counterpart foreign application, which occurred no more than three months prior to filing the Information Disclosure Statement. 37 C.F.R. §1.97(e)(1).			
	□ b.	I hereby certify that no item of information in this Information Disclosure Statement was cited in a communication from a foreign patent office in a counterpart foreign application or, to my knowledge after making reasonable inquiry, was known to any individual designated in 37 CFR §1.56(c) more than three months prior to the filing of this Information Disclosure Statement. 37 C.F.R. §1.97(e)(2).			
	□ c.	Attached is our check no in the amount of \$180 in payment of the fee under 37 C.F.R. §1.17(p). Please credit or debit Deposit Account No. 50-0860 as needed to ensure consideration of the disclosed information. Two duplicate copies of this paper are attached.			
3.	U.S. fi but bei Disclos \$130.0 Deposi	This Information Disclosure Statement is being filed more than three months after the U.S. filing date and after the mailing date of a Final Rejection or Notice of Allowance, but before payment of the Issue Fee. Applicant(s) hereby petition(s) that the Information Disclosure Statement be considered. Attached is our check no in the amount of \$130.00 in payment of the petition fee under 37 C.F.R. §1.17(i)(1). Please credit or debit Deposit Account No as needed to ensure consideration of the disclosed information. Two duplicate copies of this paper are attached.			
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4.	(other)):			

Applicant does not believe that any additional fee is due in connection with the foregoing. However, any deficiencies may be charged to the deposit account 50-0860.

Respectfully submitted,

William F. Ryann

Registration No. 44,313 Attorney for Applicant

Advanced Technology Materials, Inc.

7 Commerce Drive Danbury, CT 06810 Agent Ref: ATMI-687

FORM PTO-1449		US Dept. of Commerce		ATTORNEY DOCKET NO.		SERIAL NO.		
Patent and Trademark Office			ATMI-687	10/714,307				
				APPLICANT				
INFORMAT	ION	SOLOSURE STA	TEMENT	Xueping Xu, et al.				
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`			U.S. I	PATENT DOCUMENTS	,			D + mm
EXAMINER INITIAL	SET 1	ADEN PATENT	ISSUE DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE	
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	AB	6,455,877	9/24/2002	Ogawa, et al.				
	AC	2001/0030329	10/18/2001	Ueta, et al.				
			FOREIG	N PATENT DOCUMENTS				
		DOCUMENT NUMBER	PUBLICATION DATE	COUNTRY	CLASS	SUBCLAS S	TRANSL YES	ATION NO
							X (abstract only)	
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EXAMINER				DATE (CONSIDERED)	-	
EXAMINER citation if not	: Initia	l if citation consider	ered, whether or considered. Incl	not citation is in conformance ude copy of this form with ne	with MPE	P § 609; Draw cation to the a	line throug	gh .